# Polariton dynam ics and Bose-E instein condensation in sem iconductor m icrocavities

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We present a theoretical model that allows us to describe the polariton dynamics in a semiconductor microcavity at large densities, for the case of non-resonant excitation. Exciton-polariton scattering from a thermalized exciton reservoir is identified as the main mechanism for relaxation into the lower polariton states. A maximum in the polariton distribution that shifts towards lower energies with increasing pump-power or temperature is shown, in agreement with recent experiments. Above a critical pump-power, macroscopic occupancies (5  $10^4$ ) can be achieved in the lowest energy polariton state. Our model predicts the possibility of Bose-E instein C ondensation of polaritons, driven by exciton-polariton interaction, at densities well below the saturation density for C dTe microcavities.

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I. IN TRODUCTION

Polaritons are quasiparticles created by the strong coupling between excitons and photons, and behave as composite bosons at small enough densities. In the last decade a huge experim ental and theoretical e ort has been dedicated to the search for quantum degeneracy e ects in microcavity polaritons. They were soon proposed as candidates for the formation of a Bose-E instein condensate, due to their sm all density of states (DOS) [1]. However, a bottleneck e ect due to the slow polariton-acoustical phonon scattering was predicted [2] and observed in angle-resolved experiments [3]. Stim ulated scattering due to the bosonic nature of polaritons has been dem onstrated [4] in pum p-probe experim ents. Param etric am pli cation and param etric oscillation, under resonant excitation, has been observed [5,6] and was well explained by coherent polariton-polariton scattering [7{9]. In GaAs microcavities, experiments have shown the role of the polariton-polariton scattering in the nonlinear em ission after non-resonant excitation, either in continous wave [10{12], or tim e-resolved experin ents [13]. The growth of II-VIm icrocavities leads to new exciting possibilities due to the larger stability of the exciton. The study of these samples has allowed for the observation of stimulated scattering in the strong coupling regim e under non-resonant excitation conditions [14]. The robustness of the polariton in these sam ples has been recently shown by the dem onstration of param etric am pli cation at high tem peratures [15].

The theoretical study of sem iconductor m icrocavities has followed two di erent lines. A ferm ionic form alism, including carrier-carrier correlation, explained the lasing by population inversion at densities above the saturation density, where the coupling between the exciton and the photon disappears (weak coupling regim e) [16,17]. On the other hand, a bosonic picture, including polaritonpolariton interaction, has been developed. It must be stressed that recent experiments agree with the predictions made by the bosonic formalism (bottleneck e ect, stimulated scattering) under excitation conditions such that the density of polaritons remains below the saturation density. The polariton-polariton interaction, given by the usual C oulom b exchange interaction between excitons, and the saturation term, has also explained quantitatively many recent observations [4{8].

In this paper we present a theoretical study of the evolution of the polariton population at large densities with a bosonic description. We use the sem iclassical Boltzm ann equation, developed by Tassone et al. [18], as the starting point for the description of the polariton dynam ics. Exciton-polariton (X - P) scattering is identied as the most important mechanism for relaxation towards the low erpolariton branch. We deduce a simplied model in which the high energy excitons are considered as a therm alized reservoir. This simplication allows us to describe all the microscopic low erpolariton states, and the evolution of the polariton population towards Bose-E instein Condensation (BEC) [19].

X-P scattering is shown to produce a polariton population with an occupancy that has a maximum at a given energy below the exciton energy. The energy at which the polariton distribution peaks is shown to decrease linearly as pump-power or sample temperature is increased, in such a way that the dip in the polariton dispersion behaves as a polariton trap in phase-space [20]. This conclusion is valid for all sem iconductor m icrocavities. In particular, the same behavior has been observed in a recent experiment in a G aA s m icrocavity [10]. How ever, in G aA s, densities com parable to the saturation density are created, as one increases the pumppower, before the threshold for BEC is reached. Thus, for a clean observation of all the phenom enology described in this paper, better material parameters than those of GaAs m icrocavities are desirable. We predict that in CdTem icrocavities, where excitons arem ore stable due to their smaller Bohr radius, the threshold for BEC can be reached for densities well below the saturation density. Thus, we choose, for concreteness, CdTe parameters for the detailed calculations shown below. Our model shows that the relaxation towards the ground state is only possible for densities com parable to the saturation density in GaAsm icrocavities. In order to achieve BEC with smaller polariton densities, an additional scattering channel that those considered here should be included. E lectron-polariton scattering in doped m icrocavities has been recently proposed [21] as an e cient mechanism that allow sBEC for such sm all polariton densities.

The paper is organized as follows. In section II we present the theoretical fram ework. A set of di erential equations is obtained for the description of the m icroscopic lower polariton levels, and the exciton density and exciton temperature. In section III, we apply this model to the study of the dynam ics of the polariton population for di erent pump-powers and temperatures, after non-resonant, continuous excitation. The case of Bose-E instein C ondensation into the lowest energy polariton m ode is considered in section IV. Finally, in section V, we list our main conclusions, and discuss the com parison with experiments.

#### II. RATE EQUATION SIMPLIFIED MODEL

# A . Sim pli ed m odel for the exciton-polariton scattering

At densities such that  $na_B^2 << 1$ , where  $a_B$  is the 2-D exciton Bohr radius, excitons can be described as interacting bosons. From typical parameters for CdTe QW's (exciton binding energy  $E_B = 25 \text{ meV}$ , and electron and hole elective masses  $m_e = 0.096$ ,  $m_h = 0.2$ ), we get a 2-D exciton Bohr radius  $a_B = 47 \text{ A}$ , and  $a_B^2 = 4.5 = 10^{12} \text{ cm}^{-2}$ . On the other hand, at large exciton densities, carrier exchange interactions and phase-space lling elects destroy the coupling between excitons and photons. The density at which the exciton oscillator strength is completely screened is the saturation density,  $n_{sat}$ . Following Schmitt-R ink et al. [22], we can estimate, for a CdTe microcavity,

$$n_{sat} = \frac{0.117}{a_{eff}^2} = 6.7 \quad 10^1 \text{ cm}^{-2};$$
 (1)

where  $a_{eff}^2 = a_B = 2$ . In InG aAs and GaAsQW 's,  $n_{sat}$ would result to be 6.6  $10^{10}$  cm<sup>2</sup> and 1.3  $10^{11}$  cm<sup>2</sup>, respectively. A long this paper we consider the case of C dTe in a range of polariton densities well below  $n_{sat}$ , so that the microcavity remains in the strong coupling regime.

In the strong coupling regime, the Hamiltonian includes the coupling between excitons and photons through the polariton splitting,  $_{\rm P}$  [23]:

$$H_{0} = \sum_{k}^{X} b_{k}^{y} b_{k} + c_{k}^{c} a_{k}^{y} a_{k} + \frac{p}{2} a_{k}^{y} b_{k} + b_{k}^{y} a_{k} : (2)$$

 $b_k^y$ ,  $k_k^x$  ( $a_k^y$ ,  $k_k^c$ ) are the creation operator and dispersion relation for the bare exciton (photon) mode. The residual C oulomb interaction between excitons, and the saturation of the exciton oscillator strength, can be described by the elective exciton-exciton, and exciton-photon interaction H am iltonian [24]:

$$H_{I} = \frac{X}{\prod_{\substack{k_{1},k_{2} \\ q}}} \frac{M_{xx}}{2S} b_{k_{1}}^{y} b_{k_{2}}^{y} b_{k_{1}+q} b_{k_{2}-q} + \frac{-\frac{sat}{S}}{S} b_{k_{1}}^{y} b_{k_{2}}^{y} b_{k_{1}+q} a_{k_{2}-q} + hc:$$
(3)

where S represents the quantization area. We consider here the smallm om entum lim it for H $_{\rm I}$ , an approximation that is valid for the range of small wave-vectors considered below. The matrix elements in H $_{\rm I}$  are given by:

$$M_{xx} \qquad 6 E_B a_B^2$$
sat 1.8 P  $a_B^2$  (4)

H $_0$  can be diagonalized in the polariton basis:

$$p_{lp;k} = X_{k}^{lp} b_{k} + C_{k}^{lp} a_{k}$$

$$p_{up;k} = X_{k}^{up} b_{k} + C_{k}^{up} a_{k}$$
(5)

where X  $_{k}^{lp=up}$ , C  $_{k}^{lp=up}$  are the H op eld coe cients, that represent the excitonic and photonic weights in the polariton wave-function for the low er/upperbranch, respectively [25]. By m eans of the transform ation (5) we can express H  $_{\rm I}$  in terms of polariton operators. W e will neglect the upper polariton branch, an approximation that will be justi ed later. W e express the operators b<sub>k</sub>, a<sub>k</sub> in (3) in term s of plp; k, pup; k, and retain the term s corresponding to interactions within the low erpolariton branch only,

where

$$\frac{1}{2} \nabla_{k_{1},k_{2},k_{3},k_{4}}^{lp} = \frac{1}{2} M_{xx} X_{k_{1}}^{lp} X_{k_{2}}^{lp} X_{k_{3}}^{lp} X_{k_{4}}^{lp} + \\ sat C_{k_{1}}^{lp} X_{k_{2}}^{lp} X_{k_{3}}^{lp} X_{k_{4}}^{lp} + \\ sat X_{k_{1}}^{lp} X_{k_{1}}^{lp} C_{k_{3}}^{lp} X_{k_{4}}^{lp} + \\ k_{1} + k_{2},k_{3} + k_{4} :$$
(7)

 $\frac{1p}{k}$  is the dispersion relation for the lower polariton branch. It is plotted, assuming typical parameters for a semiconductor microcavity, in Fig. 1. For energies higher than the bare exciton energy, it matches the bare exciton dispersion.

The theoretical model developed by Tassone et al. [18] describes the evolution of the polariton population by means of a sem iclassical Boltzmann equation that includes polariton-acoustical phonon and polaritonpolariton scattering. A grid uniform in energy is considered for the description of the polaritonic levels. Here, we are interested in the evolution of the system towards a Bose-Einstein condensate. It is well known that in 2-D system s, BEC is possible at nite temperatures, only for systems with a nite quantization length, L<sub>c</sub>. As a result, the critical density and tem perature depend logarithm ically on this length scale. Due to the peculiarity introduced by the 2-D character of sem iconductor microcavities, the grid uniform in energy considered in [18] is not well suited for the study of the transition towards BEC. Instead, a uniform grid in k-space, related with the inverse of the quantization length,  $L_c^{-1}$ , has to be considered. Unfortunately, the number of levels that one has to consider for the description of the polariton dynam ics is dram atically increased, and a num erical calculation that includes all the possible polariton-polariton scattering processes is not possible. Thus, som e sim pli cation has to be done, which still allows to describe satisfactorily the polariton dynam ics, and to predict the possibility of Bose-Einstein Condensation.

In order to develop a simpli ed model for the case of non-resonant excitation, we make the following assum p-tions:

(1) The exciton population above the bare exciton energy can be considered as a reservoir at a given tem perature, that follows a M axwell-Boltzm ann distribution.

(2) The main scattering mechanism at large densities for relaxation into the lower polariton modes is the one shown in Fig. 1, in which two excitons scatter in the reservoir, and the nal states are a lower polariton, and another reservoir exciton. We will call this process exciton-polariton scattering.

A scattering process in which two excitons are initially in the exciton reservoir, and a low er and upper polariton are the nalstates is also possible, but has a much smaller probability. This is due to the fact that in such a collision, an upper polariton, instead of an exciton, plays the role of a nal state. Thus, the scattering rate is reduced by the ratio between the upper polariton and bare exciton DOS,  $_{up} = _{x} = 4 = 10^{-5}$ . In fact, for negative or zero detunings, the upper polariton population remains negligible, as shown experimentally [14] and theoretically [18]. The scattering of excitons with acoustical phonons going into low er polariton states is also much slow er than the X-P scattering already at exciton densities of  $10^{9}$  cm<sup>-2</sup>, and the lattice tem peratures considered here. The phase-space is, thus, divided into two pieces.

The exciton reservoir, which describes the excitons directly created by the non-resonant pump. We take as zero energy the bare exciton energy, so that the exciton reservoir includes all the levels with

> 0. These levels are weakly coupled to the photonic modes, so that they can be approximated as bare excitons. The occupation numbers are given by,

$$N_{i}^{x} = N^{x} e^{\sum_{i=k_{B}}^{x} T_{x}}$$
(8)

N<sup>x</sup> is given by

$$N^{x} = \frac{2 n_{x}}{k_{B} T_{x}}; \qquad (9)$$

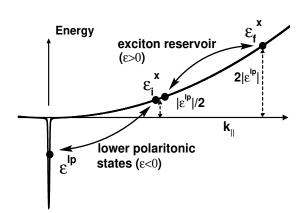
where  $n_x$  is the exciton density, x is the bare exciton density of states,

$$x = (m_e + m_h) = h^2;$$
 (10)

and  $T_x$  is the tem perature of the exciton reservoir. The assumption of a rigid therm al exciton distribution is well justi ed, as discussed below, for levels above = 0, due to the fast exciton-exciton scattering that them alize the exciton population at large densities [18,26]. On the other hand, a Maxwell-Boltzmann distribution, rather than a Bose-E instein distribution can be used to describe the exciton reservoir, provided that N  $^{\rm x}$  << 1. Ν× 02 for the largest densities considered here, so that quantum degeneracy e ects are negligible. The main mechanism for radiative losses in the exciton reservoir is due to the coupling to the leaky modes, that we include by considering an exciton lifetime, x = 100 ps [27].

The lower polariton branch (LPB), where the energy levels are below the bare exciton energy ( $_{\rm k}^{\rm lp}$  < 0). Exciton and photon levels in the LPB are strongly coupled, and radiative losses are much more important, due to the photonic weight of these states. Thus, we expect a nonequilibrium polariton distribution that depends strongly on tem – perature and density. On the other hand, the abrupt dispersion relation implies a very small effective mass for the LPB states, m  $_{\rm lp}$  4 10  $^5 {\rm m}_{\rm x}$ , leading to the possibility of Bose-E instein C ondensation.

W ith this separation of the phase-space we are neglecting the details of the polariton population near 0, that is, at the knee in the polariton dispersion relation, where the LPB and the quadratic dispersion of the bare excitons m erge together (see Fig. 1). The contribution from these states is negligible already at the lowest tem – peratures considered here (4K,  $k_B\,T\,$  0.35m eV), because the main part of the exciton distribution is in the weak coupling region.



reservoir into and out of the LPB, due to the interaction H am iltonian (3) are calculated in Appendix A. They lead to a simpli ed version of the sem iclassical Boltzm ann equation:

$$\frac{dN_{k}^{lp}}{dt} = 
\frac{dn_{x}}{dt} = 
\frac{dn_{x}}{dt} = 
\frac{\frac{dn_{x}}{dt}}{\frac{dn_{x}}{dt}} = 
\frac{1}{S} \sum_{k}^{X} dg_{k}^{lp} (W_{k}^{ln} n_{x}^{2} (1 + N_{k}^{lp}) - W_{k}^{out} n_{x} N_{k}^{lp}) \\
= (12)$$

 $_{k}^{p}$ , x are the radiative losses in the LPB and exciton reservoir, respectively:

FIG.1. Exciton-polariton scattering process from a thermalized exciton reservoir into the lower polariton branch.

W e describe the LPB states by a grid in k-space. The exact quantization area is not well determ ined in experiments, due to inhom ogeneities in the spot, and surface defects. The relevant quantity is the quantization length, that gives the order of magnitude for the distance between the energy levels. We consider rst  $L_c = 50 \text{ m}$  (a typical excitation spot diameter), and plane waves for the microscopic polariton states, so that the quantization area is simply  $S = L_c^2$ . The allowed wave-vectors are given by

$$k^{lp} = (n_x x + n_y y) \frac{2}{L_c};$$
 (11)

where  $n_x; n_y$  are integers. A similar method has been employed to describe the microscopic polariton levels in a microcavity etched into a microscopic post structure  $(L_c = 2 \text{ m})$  [28]. In that case, the LPB is reduced to a single microscopic level. On the contrary, in our case,  $L_c$  is larger, and the number of lower polariton levels results to be of the order of  $10^3$ . The main results of our work do not depend strongly on the exact value of  $L_c$ , but only on its order of magnitude, as we show in the last section. The weak dependence of our results on  $L_c$ can be easily understood from the peculiarities of BEC in 2-D (see Appendix B).

W e write now a set of rate equations for N  $_{k}^{lp}$  (occupation numbers in the lower polariton branch) and n<sub>x</sub> (the density of the therm alized exciton reservoir). We consider the injection of polaritons from isotropically distributed excitons, so that the occupation numbers N  $_{k}^{lp}$  will depend on the absolute value of the in-plane wave-vector only. The rates for scattering from the therm alized

where  $_{\rm c}$  is the lifetime for the bare photon within the cavity. We consider  $_{\rm c}$  = 1ps, a typical value for high quality m icrocavities.  $p_{\rm x}$  represents the non-resonant pump that injects excitons directly into the exciton reservoir. If relaxation into the LPB is slow enough, the lifetime for an exciton in the exciton reservoir is given by  $_{\rm x}$ , so that a given pump  $p_{\rm x} = n_{\rm x} = _{\rm x} = n_{\rm x} = 100 \text{ps}$  creates an exciton density  $n_{\rm x}$ . If scattering into the LPB is fast enough, how ever, the density created by the pump p is smaller, as we will see below.  $dg_k^{\rm ip}$  is the degeneracy for the polariton level corresponding to the wave-vector k, and is calculated according to the distribution obtained from Eq. (11).

W  $_{k}^{in}n_{x}^{2}$ , W  $_{k}^{out}n_{x}$  are the rates for X-P scattering into and out of the LPB. They are given by the expressions (see Appendix A):

$$W_{k}^{in} = \frac{2}{hk_{B}T_{x}}M_{k}^{2}e^{\frac{lp}{k}=k_{B}T_{x}}$$
$$W_{k}^{out} = \frac{1}{h}M_{k}^{2}xe^{2k_{k}^{lp}=k_{B}T_{x}}; \qquad (14)$$

where

$$M_{k} = M_{xx}X_{k}^{lp} + _{sat}C_{k}^{lp}$$
(15)

The dependence of the rates on temperature can be qualitatively understood by the phase-space restrictions for relaxation into and out of the LPB (Fig. 1). Let us consider two excitons in the exciton reservoir with a wave-vector  $k_i^x$  and energy  $_i^x$ , that scatter to a LPB state with energy  $_k^{lp}$  and to a high energy state with  $k_f^x$ ,  $_f^x$ . Taking into account that the wave-vector of the lowenergy polariton is negligible, when compared with the wave-vectors in the reservoir, simultaneous energy and momentum conservation implies that:

$$2 j_{k_{1}}^{x} j = j_{f}^{x} j! \quad 4 j_{f}^{x} = f_{f}^{x}$$

$$2 j_{i}^{x} = j_{k}^{j_{p}} j+ j_{f}^{x} ! \quad j_{i}^{x} = j_{k}^{j_{p}} j=2; \quad f = 2 j_{k}^{j_{p}} j: \quad (16)$$

Eq. (16) m eans that two excitons need an energy  $j_k^{lp} \neq 2$  to be the initial states of a process in which one of them falls into the LPB.On the other hand, an exciton needs an energy  $2 j_k^{lp} j_k^{lp}$  in order to scatter with a low erpolariton and take it out of the LPB.

The polariton distribution in the steady-state regime will be given by the set of equations (12) with  $dN_k^{lp} = dt = 0$ ,  $dn_x = dt = 0$ . In the steady-state, the occupation numbers in the LPB are given by:

$$N_{k}^{lp} = \frac{W_{k}^{in} n_{x}^{2}}{W_{k}^{out} n_{x} + \frac{lp}{k} - W_{k}^{in} n_{x}^{2}} :$$
(17)

If we neglect the dependences on k of the m atrix element M  $_k$  and the radiative losses  ${}^{lp}_k$ , then the m axim um in the polariton distribution has a peak at the energy:

$$j_{m ax}^{lp} j = \frac{1}{2} k_B T_x \log \frac{1}{h^{lp}} M^2 x n_x$$
 (18)

Eq. (18) implies an approximately linear relation between the exciton reservoir temperature and the energy position at which the system prefers to relax into the LPB (that is, the maximum energy loss in the relaxation process).

# B.M odel for the evolution of the exciton reservoir tem perature

The strong dependence of the X-P scattering into the LPB on  $T_x$  in plies that, in order to complete ourm odel, we have to describe properly the evolution of the exciton reservoir temperature. During the relaxation process into the LPB, shown in Fig. 1, a high energy exciton is injected into the exciton reservoir. This way, during the relaxation process, the exciton reservoir is heated. On the other hand, the scattering with acoustical phonons, tries to keep the exciton reservoir at the lattice temperature. In order to describe the evolution of the exciton reservoir temperature, a new variable has to be added to this set of equations. We introduce  $e_x$ , the density of energy for the exciton reservoir, that is given, for a M axwell-B oltzm ann distribution, by the expression:

$$e_{x} = \frac{1}{S} \sum_{k}^{X} N_{k}^{x} \sum_{k}^{x} = n_{x} (k_{B} T_{x}); \qquad (19)$$

The evolution of the energy allows us to obtain the exciton temperature, at each step in the evolution of the polariton population.

However, we still need to make an assumption about the exciton distribution that the pump directly injects into the reservoir. Non-resonant experim ents usually create a population of high energy electron-hole pairs, that relax towards low energy states, after the process of exciton formation [2,29]. It must be stressed that for the case of C dTe QW 's this process is particularly fast, due to the possibility of exciton form ation through the em ission of LO phonons, whose energy is 21 m eV, below the exciton binding energy (25 m eV). The time scale for thermalization due to exciton-exciton scattering is very fast 1ps), as compared with the time scale for relaxation ( into the LPB ( 20ps, for the larger exciton densities considered here). Thus, it is very well justi ed to describe the non-resonant pump, as a source that injects therm alized excitons at a given pump-tem perature into the exciton reservoir. We still need to specify which is the initial pump-tem perature. Due to the large uncertainties in non-resonant experiments it is very difcult to make predictive calculations about this initial condition. We choose instead to make the simplest assum ption: we consider that the pum p in jects excitons at the lattice tem perature, TL. For large exciton densities (above 5  $10^{10}$  cm  $^2$ ) the processes of reservoir heating by X-P scattering and cooling through exciton-phonon scattering, govern the nalexciton tem perature, and our results do not depend on our assumption for the pumptem perature. For sm all tem peratures (below 10 K), and densities, our results depend on this assumption. In a real experiment, the exciton temperature can be larger than the one considered here, if the cooling of the initial non-resonantly created excitons is not fast enough.

It must be pointed out that a very e cient experim ental setup for non-resonant excitation of a cold exciton distribution in a sem iconductorm icrocavity has been dem onstrated by Savvidis et al. [10]. In this experim ent, non-resonant excitation has been achieved with sm allexcess energies (below the stop band), due to the nite transm ittance of the B ragg re ectors. The experim ental results presented in [10] are in agreem ent with a m odel in which excitons relax from a therm alized distribution into the low est energy states, and justify all the assumptions m ade above.

We have to quantify the three contributions for the evolution of the exciton temperature listed above:

(i) Heating by the scattering to high energy exciton levels.

The total energy is conserved in the X -P scattering towards the LPB. Thus, the energy lost by the polaritons falling into the lower energy states must be gained by the exciton reservoir. The following expression gives the rate of change of  $e_x$  by each X -P scattering process:

$$\frac{\mathrm{d}\mathbf{e}_{x}}{\mathrm{d}t} \mathbf{\dot{x}}_{P} = \frac{1}{S} \sum_{k}^{k} \frac{\mathrm{l}_{p}}{k} \mathrm{d}\mathbf{g}_{k}^{\mathrm{l}p}$$

$$(W_{k}^{in}n_{x}^{2}(1+N_{k}^{lp}) W_{k}^{out}n_{x}N_{k}^{lp}):$$
 (20)

The heating of the exciton gas in the relaxation towards the LPB was also shown theoretically in [28], for the case of a microcavity post.

#### (ii) Cooling produced by acoustical phonons.

The exciton-phonon scattering tries to keep excitons at the lattice tem perature,  $T_{\rm L}$ , against the heating considered above [26]. We divide the exciton M axwell-Boltzm ann distribution into levels equally spaced in energy with a given  $E << k_{\rm B} T_{\rm L}$ ;  $k_{\rm B} T_{\rm X}$ . The probability for absorption or emission of acoustical phonons gives a scattering rate W  $_{j!\ i}^{\rm ph}(T_{\rm L})$  for the transition between states with energies  $_{i}^{\rm x}$ ;  $_{j}^{\rm x}$ . These rates depend on the phonon distribution through  $T_{\rm L}$ , and can be evaluated from the exciton-acoustical phonon interaction H am iltonian. The evolution of the occupation numbers, N  $_{i}^{\rm x}$ , in the exciton reservoir leads to an expression for the rate of change of the total energy:

$$\frac{de_{x}}{dt} \dot{p}_{h} = \frac{x}{2}^{X} \qquad E \qquad \stackrel{x}{i} \frac{dN_{i}^{x}}{dt} \dot{p}_{h} =$$

$$= \frac{x}{2}^{X} \qquad \stackrel{x}{i}^{X} \qquad W \qquad \stackrel{ph}{j! i} (T_{L}) N \qquad \stackrel{x}{j} \qquad W \qquad \stackrel{ph}{i! j} (T_{L}) N \qquad \stackrel{x}{i}$$

$$= \frac{E n \qquad x}{k_{B}} T_{x} \qquad \stackrel{i}{i} \qquad \stackrel{x}{i}$$

$$\qquad W \qquad \stackrel{ph}{j! i} (T_{L}) e \qquad \stackrel{\stackrel{x}{j}=k_{B}}{T_{x}} \qquad W \qquad \stackrel{ph}{i! j} (T_{L}) e \qquad \stackrel{x}{i}=k_{B} T_{x}$$

$$(21)$$

For the calculation of W  $^{\rm ph}$  we have used the exciton-acoustical phonon coupling through the deform ation potential interaction. These rates have been presented in several previous works [18,26,29], and we will not rewrite them here. We consider deform ation potentials  $a_e=2$ :leV,  $a_h=5$ :leV for CdTe [30], and an 80A QW. In Eq. (21), stimulated terms are neglected, due to the sm all occupation numbers in the exciton reservoir. The rate of change for  $e_x$  results to be linear in  $n_x$ , and dependent on both  $T_{\rm L}$  and  $T_{\rm x}$ .

(iii) Cooling to the pump tem perature.

The injection of excitons into the reservoir by a pump that is considered to be at the lattice temperature tries to keep the exciton reservoir at  $T_L$ . The terms that correspond to pumping and radiative losses in Eqs. (12),

$$\frac{dn_x}{dt} \dot{p}_u = p_x \qquad x n_x; \qquad (22)$$

im ply that the rate for the evolution of the occupation numbers has the contribution:

$$\frac{dN_{k}}{dt}\dot{p}_{u} = \frac{2p_{x}}{xk_{B}T_{L}}e^{-\frac{x}{k}=k_{B}T_{L}} \qquad x\frac{2n_{x}}{xk_{B}T_{x}}e^{-\frac{x}{k}=k_{B}T_{x}};$$
(23)

where the condition that the pump in jects excitons at  $T_L$  into a M axwell-Boltzm ann distribution at  $T_x$  is included. The rates in Eq. (23) leads to a new contribution to the evolution of  $e_x$ :

$$\frac{d\mathbf{e}_{x}}{dt} \dot{\mathbf{p}}_{u} = \frac{1}{S} \sum_{k}^{X} \frac{dN_{k}^{X}}{dt} \dot{\mathbf{p}}_{u} = p_{x}k_{B}T_{L} \frac{n_{x}}{x}k_{B}T_{x}: \quad (24)$$

N ote that this contribution cools the exciton reservoir if  $T_{\rm x} > ~T_{\rm L}$  .

The set of rst-order di erential equations (12), together with (20, 21, 24), leads to a closed description for the dynam ics of the exciton reservoir and lower polaritons. We have integrated numerically these equations until the stationary solution (dN  $^{lp}=dt = dn_x=dt =$  $de_x=dt = 0$ ) is reached. The obtained solution describes the steady-state for the case of a continuous non-resonant pump.

C.Com parison between our sim pli ed model and the com plete sem iclassical Boltzm ann equation.

We have checked whether the polariton distribution obtained with this simplied model agree with the one obtained in a detailed calculation performed with a Boltzmann equation in which the simplifying assumption of a Maxwell-Boltzmann distribution for the levels in the exciton reservoir is not made. In Fig. 2 we present the comparison between a complete calculation that follows reference [18], with a grid uniform in energy (E = 0:1m eV), in which all the polariton-polariton and polariton-phonon scattering processes are included, and our simplied model. We expect that the results from both calculations coincide under conditions for which Bose-Einstein Condensation (that is, the macroscopic occupancy of a single m icroscopic mode) is not possible. On the contrary, in the range of densities near or above BEC, com parison between both models would not be allowed because the system would not be free to relax into a single m icroscopic m ode. Thus, a continuum density of states would not be able to describe properly the LPB, and a grid uniform in energy could not be applied. In Fig. 2 a few pump-powers have been chosen, for which the comparison is possible. It can be clearly seen that both calculations yield identical results, so that, we can conclude that our sim pli ed m odel captures the essential physics in the relaxation from the exciton reservoir towards the lower energy polariton states.

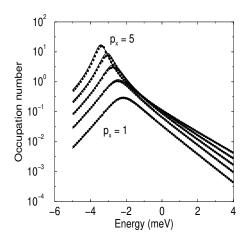


FIG.2. Polariton distribution calculated by means of the complete sem iclassical Boltzm ann equation, as in Ref. [18] (points), and polariton distribution calculated by means of our simpli ed model (continuous line). We have considered a CdTe microcavity with zero detuning and  $T_L = 10K$ . The curves, from bottom to top, refer to pump-powers from 1 to 5, in units of  $10^{10}$  cm<sup>2</sup>=100ps.

# III. EVOLUTION OF THE POLARITON DISTRIBUTION W ITH PUMP-POWER AND TEMPERATURE

#### A.Evolution with tem perature

In the previous section, we obtained an estimation for the evolution of the polariton population as the exciton tem perature Tx is increased. A rough linear relation between the position of the maximum in the distribution and Tx was predicted. Now we present a com plete calculation with our model that con m s this estimate. This e ect can be observed for a di erent range of polariton splittings and detunings. How ever, the main param eter that governs the relaxation from the exciton reservoir is the energy di erence between the bare exciton and the bottom of the LPB. This energy distance can be interpreted as the depth of the polariton trap form ed by the dip in the polariton dispersion. W ithin this paper we will consider, for concreteness, the case of zero detuning (that is,  $E_x$  (bare exciton energy) =  $E_c$  (bare photon energy)), so that the lowest polariton mode has an energy  $_{\rm P}$  =2 below  $E_X$  .

In Fig. 3 we show the evolution of the polariton distribution for  $_{\rm P}$  = 10m eV. We choose  $p_{\rm X}$  =  $10^{10}$  cm  $^2$ =100ps. Under such excitation conditions, X-P scattering is slower than radiative recombination in the exciton reservoir, and  $n_{\rm X}$  \_ xp<sub>X</sub>. The heating of the exciton gas is also negligible, so that  $T_{\rm X}$  \_  $T_{\rm L}$ . The peak in the polariton distribution m oves tow ands lower energies as tem perature is increased. D ue to the fact that the rate given in Eq. (14) for scattering into the LPB decreases

with  $T_{\rm x}$ , smaller occupation numbers are predicted for higher temperatures. At high  $T_{\rm x}$ , the bottleneck is suppressed and the polariton distribution becomes almost at. The di erence between high and low  $T_{\rm x}$  was already observed in [11], where a at distribution was evidenced for pum p-powers where the X-P scattering is the dom inant relaxation mechanism .

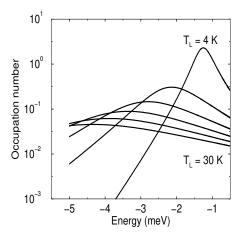


FIG. 3. Evolution of the polariton distribution for  $T_{\rm L}$  = 4;10;15:::30K ,  $_{\rm P}$  = 10 meV , zero detuning, and  $p_x$  =  $10^{10}\,cm^{-2}$ =100ps.

The evolution of the peak in the polariton distribution is shown in Fig. 4 for a range of polariton splittings. The linear dependence predicted by the estimation in Eq.(18) is clearly observed. For high enough temperatures and small energy distance between the lowest polariton energy and the exciton reservoir, the maximum in the polariton distribution can reach the bottom of the LPB. However, the occupation numbers are still smaller than one, and the situation is not able to produce BEC.

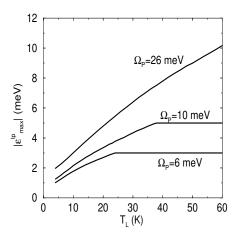


FIG.4. Dependence of the energy of the peak in the polariton distribution on  $T_L$  for  $p_x = 10^{10}$  cm<sup>2</sup>=100ps, and different polariton splittings.

D ue to the isotropy of the low er polariton distribution, the em ission at a given energy  $\frac{lp}{m}_{ax}$ , corresponds to em ission at a given angle with the grow th axis. Them ovem ent of  $\frac{lp}{m}_{ax}$  towards low er energies in plies that the sam ple em its light preferentially in a ring, at a given angle that decreases with tem perature. The recent experiment reported by Savvidis et al. [10] has observed the ring em ission with the linear dependence on lattice tem perature described above, and show s that the X-P scattering from a therm alized exciton reservoir considered here, is the m ain scattering m echanism for relaxation into the LPB.

#### B.Evolution with Pum p-Power

As shown in Eq. (18),  $\frac{lp}{m}_{ax}$  depends logarithm ically on the exciton density, and linearly on  $T_x$ . At large densities, however, the heating of the exciton reservoir must be properly taken into account. When occupation numbers N<sub>k</sub><sup>lp</sup> > 1 are achieved, the X-P scattering mechanism shown in Fig. 1 is stimulated, and the injection of high energy excitons becomes more and more important. In this situation, the heating of the exciton reservoir govems the evolution of  $\frac{lp}{m}_{ax}$  as  $p_x$  is increased, because for higher  $T_x$ , the polariton distribution has a maximum at lower energies. This way, the heating of the exciton trap form ed by the dip in the polariton dispersion.

Fig. 5 shows the evolution of the polariton distribution as one increases the pum p-power. The distribution can reach the lowest energy state and large occupation numbers can now be achieved. For large enough powers, the lowest energy state can have the main part of the polariton population, a situation that will be described in detail in section IV. For intermediate pum p-powers, occupation numbers larger than one are obtained form odes with k  $\stackrel{6}{\leftarrow}$  0. Thus, ourmodel predicts the stimulation towards these modes before BEC is achieved.

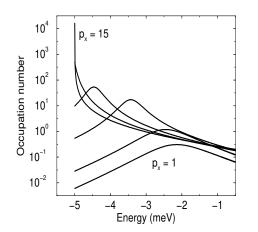


FIG. 5. Evolution of the polariton distribution for  $T_L$  = 10K,  $_P$  = 10meV, and  $p_x$  = 1;2;5;8; 15  $10^{10}$  cm  $^2$ =100ps (from bottom to top).

In Fig. 6 we show the evolution of  $\frac{lp}{max}$ , as one increases  $p_x$ , for dierent P's. Three stages can be  $10^9 {\rm cm}^2 = 100 {\rm ps}$  to clearly distinguished. From px px  $10^{10}$  cm <sup>2</sup>=100ps, the exciton density created by the pump is sm allenough for the heating of the exciton reservoir to be neglected. Under such conditions, the evolution of  $\frac{lp}{max}$  is governed by the logarithm ic dependence on  $10^{10}$  cm <sup>2</sup>=100ps,  $p_{x x}$  (see Eq. 18)). Above  $p_x$ nx the heating of the exciton gas is in portant, and the evolution of  $\frac{lp}{m}_{ax}$  is governed by the evolution of  $T_x$ , through the linear dependence shown in Eq. (18). In this regime,  $^{\rm lp}_{{\rm m\,\,ax}}$  results to depend linearly on  ${\rm p}_{\rm x}\,$  , until it saturates to the bottom of the LPB.

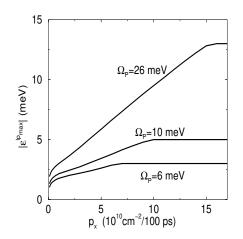


FIG.6. Dependence of the energy of the peak in the polariton distribution on pum p-power, for  $T_{\rm L}$  = 10K , and di erent polariton splittings.

The heating of the exciton reservoir is shown in Fig. 7. For large pump-powers excitons are no longer at the tem perature  $T_L$ , at which they are initially injected. The raise of  $T_x$  becomes more important for larger  $_P$  due to the highest energies of the excitons injected into the reservoir by the X-P scattering (see Fig. 1).

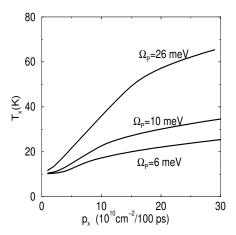


FIG.7. Dependence of the temperature of the exciton reservoir on pump-power for  $T_{\rm L}$  = 10K , and di erent polariton splittings.

At large  $p_x$ ,  $X \cdot P$  scattering is faster than the radiative recombination given by  $_x$ , an it becomes the main mechanism for losses in the exciton reservoir. Thus, the exciton-polariton density,  $n_{xp}$  (that is, the density of excitons in the reservoir plus the density of lower polaritons), created by the pump is smaller than  $p_x$ . Fig. 8 shows the evolution of the steady-state polariton density as  $p_x$  is increased. For all the three polariton density is very sim ilar.

 $\Omega_{p}=26 \text{ meV}$ 

FIG.8. Dependence of the total exciton reservoir and lower polariton density,  $n_{\rm xp}$ , on pum p-power, for  $T_{\rm L}$  = 10K . The results for  $_{\rm P}$  = 6, and 10m eV are indistinguishable.

The shift of  $\frac{lp}{max}$  towards lower energies results also in the emission in a ring at an angle that decreases as pum p-power is increased. In the experiments performed by Savvidis et al. [10], this elect was observed, and a linear relation between  $\frac{lp}{max}$  and pum p-power was reported. In this experiment, the extrapolation of the linear dependence of  $\frac{lp}{max}$  on  $p_x$  towards small powers shows an energy o set, in agreement with the theoretical result (see Fig. 6). A ngle-resolved measurements allow, thus, to monitor the evolution of the polariton population towards the ground state.

As shown in Fig. 5 for interm ediate pump-powers the system does not relax down to the ground state, but stimulation (occupancy larger than one) is achieved in the scattering into interm ediate modes with k  $\in$  0. The stimulated modes will thus emit light at angles  $\in$  0. Fig. 9 presents the evolution of the occupation numbers for them odes corresponding to di erent angles, as pumppower is increased. The evolution of the occupancy at each angles matches the experimental results in [10].

Fig. 5 and Fig. 8 allow to estimate the  $n_{xp}$  at which the relaxation into the ground state is possible. In Fig. 5 pump-powers above 5  $10^{10}$  cm<sup>2</sup>=100ps correspond to polariton densities larger than 4  $10^{10}$  cm<sup>2</sup>. Thus, in G aAs m icrocavities, the weak coupling regime will be reached before  $\frac{lp}{m}$  reaches the bottom of the LPB dispersion, due to the sm all  $n_{sat}$ , and BEC is not possible. For the clean observation of the com plete evolution of the polariton distribution towards the ground state, CdTe m icrocavities are prom ising candidates because  $n_{xp}$  rem ains wellbelow  $n_{sat}$ , before the system relaxes towards the ground state.

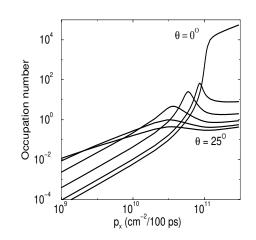


FIG.9. Evolution of the occupancy of the modes corresponding to emission angles = 0;5:::25 degrees (from right to left), as pump-power is increased.  $T_{\rm L}$  = 10K,  $_{\rm P}$  = 10m eV .

A quadratic relation is predicted, followed by an exponential grow th that saturates at large powers. Stim ulation can be observed, at polariton densities below the BEC, at given angles, which correspond to the modes where the polariton distribution peaks, as shown in Fig. 5. The saturation of the emission at a given angle is related to the evolution of the polariton population that "shifts downwards" in energy, due to the heating of the exciton reservoir. Thus, the emission at a given angle saturates when the peak in the polariton distribution turns to sm aller angles, as pum p-power is increased.

#### IV.BOSE-EIN STEIN CONDENSATION OF POLARITONS

In the previous section it was shown that X - P scattering is e cient enough to create a quasi-therm alpopulation into the LPB.W ewill quantify now in detailhow the occupancy of the lowest energy polariton state evolves when the polariton density is increased.

Above a critical pump-power, the continuous Bose-Einstein distribution shown in Fig. 5 saturates, and the additional excitons added by the pump fall into the bottom of the LPB. Thus, the lower polariton distribution becom es discontinuous, and an abrupt increase is achieved in the number of polaritons in the lowest m icroscopic level, N<sub>0</sub>. Above the threshold for BEC, the macroscopic occupancy of a single microscopic mode opens the possibility for spontaneous sym metry breaking and the appearance of coherence in that mode. The interaction between the Bose-E instein condensate and the low energy polariton modes would lead then to the reconstruction of the polariton spectrum, as predicted in the well known Bogoliubov approach [31]. These e ects can modify the relaxation dynam ics above threshold, so that our results are not rigorous in this range. However we can predict the critical density and tem perature for BEC, and the most favorable conditions for its observation.

Fig. 10 (left) shows the evolution of N $_0$ , as a function of  $p_x$ , for di erent lattice tem peratures and polariton splittings. For large  $p_x$  above the critical pum p, the relation between N $_0$  and  $p_x$  becomes linear, and occupation numbers of the order of 5 $10^4$  polaritons can be reached in the ground state. In order to interpret the evolution of the ground state occupancy, it is interesting to plot N $_0$  (Fig. 10 (right)) as a function of the steady-state exciton-polariton density,  $n_{\rm XP}$ .

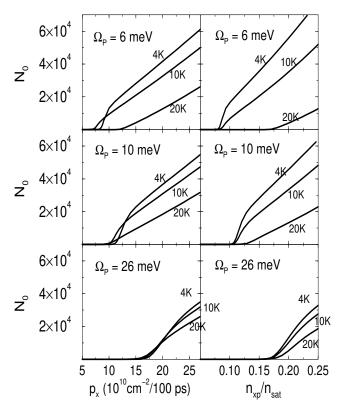


FIG.10. Left: Evolution of the occupancy of the lowest m icroscopic polariton level, as a function of the pump-power. For each polariton splitting we consider  $T_{\rm L}~=~4;10;20K$ . Right: Same as above, but now the occupancy of the lowest m icroscopic level is plotted as a function of the steady-state exciton-polariton density.

The abrupt increase in N $_0$  allows us to estim ate a critical density  $n_{\rm xp}^{\rm c}$  for BEC, which results to be around 0:1n\_{sat}. However, the situation is now not so clear as in the case of equilibrium BEC, where one expects that N $_0$  follows the relation (see Appendix B):

$$\frac{N_0}{S} = n_{xp} \quad n_{xp}^c :$$
 (25)

That is, for densities above  $n_{xp}^c$ , all the excitons added to the system should fall into the ground state. Fig. 10 (right) shows that, for large densities, the linear relation is satis ed. However, close to  $n_{xp}^c$ , N<sub>0</sub> shows a superlinear dependence on  $n_{xp}$ . This fact can be interpreted as follows. The equilibrium BEC relation between N<sub>0</sub> and  $n_{xp}$ would be given by the extrapolation of the linear regime of the curves in Fig. 10 (right), towards N<sub>0</sub> 0. By this method, we would obtain the equilibrium  $n_{xp}^c$ , which is smaller than the one we get from our complete nonequilibrium calculation. This means that in a realm icrocavity,  $n_{xp}^c$  is larger than the one predicted by equilibrium BEC.0 byiously, this is due to the radiative losses in the LPB, and also to the fact that the system has to evolve towards the ground state, following the steps described in the previous section. Thus, the X-P scattering has to overcome the radiative losses, and the exciton reservoir has to be heated, so that relaxation into the ground state becomes e cient enough. The nonequilibrium critical density has to be larger than the equilibrium one, for these conditions to be full led.

The transition from superlinear to linear dependence of N<sub>0</sub> as a function of  $p_x$ , and  $n_{xp}$ , is rejected in the evolution of the exciton reservoir temperature,  $T_x$ . Fig. 7 shows that the heating of the exciton gas slows down for the pump-power for which the linear growth of N<sub>0</sub> starts (see Fig. 10, left panel,  $_P = 10 \text{m eV}$ ). The same behavior in the evolution of  $T_x$  has been obtained for all the  $_P$ 's considered.

We can also see in Fig. 10, that for small polariton splittings, smaller pump-powers and polariton densities are needed for BEC, because the energy distance between the bottom of the LPB and the exciton reservoir is also smaller. For large  $_{\rm P}$ , the exciton gas reaches higher temperatures in the steady-state regime, and the X-P scattering rates are slower (thus, larger polariton densities are needed in order to get BEC). However, in all cases considered in both gures, the critical density is well below  $n_{\rm sat}$ .

Up to now we have assumed  $L_c = 50 \text{ m}$ , of the order of typical spot diam eters. However,  $L_c$  is not a well determ ined quantity in experiments. Equilibrium BEC in 2-D systems predicts that both critical density and tem - perature depends only on the order of magnitude of  $L_c$ . In order to check what happens in our nonequilibrium situation, we have calculated the density of polaritons in the ground state, N<sub>0</sub>=S, for di erent quantization lengths (see Fig. 11).

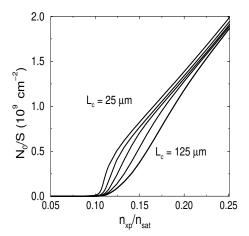


FIG.11. Evolution of the density of polaritons in the lowest microscopic state, as the exciton-polariton density is increased, for dierent quantization lengths,  $L_{\rm c}=25;50~125$  m, and  $_{\rm P}=10m$  eV ,  $T_{\rm L}=10K$ .

The occupancy of the lowest polariton mode has a

m ore abrupt increase for smaller  $L_{\rm c}$ . However  $n_{\rm xp}^{\rm c}$  is of the order of  $0.1n_{\rm sat}$  for all the quantization lengths considered.

# V.CONCLUSIONS

Ourmain conclusions are: (i) At large densities, relaxation after continuous non-resonant excitation can be described by a model in which low erpolaritons are injected from a thermalized exciton reservoir by X-P scattering. (ii) O urm odel show sa linear relation between the energy of the maximum in the lower polariton distribution and the exciton tem perature or pum p-power. By increasing the exciton density, the heating of the exciton reservoir allows the excitons to overcome the phase-space restrictions and fall into the LPB, that becomes a polariton trap in reciprocal space. (iii) Bose-Einstein Condensation is possible for densities well below n<sub>sat</sub> for C dTem icrocavities. (iv) The most favorable conditions for BEC are small polariton splittings, due to the smaller di erence between the bare exciton energy and the bottom of the LPB. (v) Our results have a weak dependence on the quantization length, which is taken as the excitation spot diam eter.

Up to now, non-resonant experiments performed in GaAs microcavities con m that the weak coupling regim e is reached before X -P scattering allow spolaritons to relax towards the ground state [10,12]. Experimental evidence for the interm ediate stage in the evolution of the polariton distribution has been achieved in a GaAs m icrocavity [10], and the experim ental results agree very well with the results presented in section III. In CdTe, experim ental evidence for stim ulation towards the lower polariton states has been achieved under pulsed nonresonant excitation. The angle-resolved m easurem ents after pulsed excitation in CdTe presented in [32] qualitatively agree with our results for the evolution of the polariton distribution as pum p-power is increased. How ever, the physical situation in pulsed experiments is quite di erent than the one considered here, because the system is not allowed to reach the steady-state in the relaxation process. Continuous wave excitation seems to be a cleaner experim ental situation for the study of the evolution of the polaritons towards a quasi-equilibrium distribution. Our model allows to predict not only the possibility of BEC, but also quantitatively describes the evolution of the system towards the ground state. Angleresolved m easurem ents under continuous non-resonant excitation would allow to show the macroscopic occupancy of the k = 0 m ode, and also to m on itor the evolution towards BEC as pum p-power is increased.

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# APPENDIX A:CALCULATION OF THE X-P SCATTERING RATES

The calculation of the rates for the scattering of thermalized excitons into the LPB was performed in [18]. Here we reproduce, for clarity, the main steps, and calculate also the rate for ionization out of the LPB.

We consider st the process that in jects polaritons. It is given by:

$$\mathbb{W}_{k}^{in} n_{x}^{2} (1 + N_{k}^{lp}) = \frac{4}{2}$$

$$\frac{4}{h^{3}} \mathbb{M}_{k} \frac{2}{J}_{x}^{3} \quad \mathbb{R} \left( {}_{i}^{x}; {}_{j}^{x}; {}_{f}^{x}; {}_{k}^{lp} \right)$$

$$N_{i}^{x} N_{j}^{x} (1 + N_{k}^{lp}) d_{i}^{x} d_{j}^{x}:$$
(A1)

N<sup>x</sup><sub>i</sub>, N<sup>x</sup><sub>j</sub> are the occupation numbers for the initial excitons in the reservoir, and N<sup>x</sup><sub>f</sub>, N<sup>lp</sup><sub>k</sub> correspond to the nal exciton and lower polariton, respectively. The N<sup>×</sup> in the thermalized exciton reservoir follow the relation (8). D ue to their large density of sates we can neglect the stimulation terms in the exciton reservoir (N<sup>×</sup> << 1). Energy conservation is implicit in Eq. (A1), so that  $f = i + j = \frac{lp}{k}$ . The function R describes the phase-space restrictions for the problem of exciton scattering in 2-D, under the approximation of isotropic exciton distributions. It can be expressed in terms of the corresponding in-plane m omenta [18]:

$$R_{Z} \begin{pmatrix} x \\ i \end{pmatrix} \begin{pmatrix} x \\ j \end{pmatrix} \begin{pmatrix} x \\ j$$

where integration is limited to the interval where the argument of the square root is positive. A great simplication is obtained when we take the limit  $k^{lp} << k^{x}$ :

If we insert this expression into (A1), we obtain

$$W_{k}^{in} = \frac{2}{\frac{h}{Z}(k_{B}T_{x})^{2}} M_{k} J^{2}$$

$$\frac{1}{\frac{r}{\frac{1}{\frac{x}{j}} \frac{x}{j}} \frac{1}{\frac{h}{z}} = 2^{2}} e^{(\frac{x}{j} + \frac{x}{j}) = k_{B}T_{x}} d_{j}^{x} d_{j}^{x}; \quad (A 4)$$

which after integration in energy gives the expression re-ported in Eq. (14).

The calculation of the rates for scattering out of the LPB follows the same way:

$$W_{k}^{out}n_{x}N_{k}^{lp} = \frac{4}{2}$$

$$\frac{4}{h^{3}}M_{k}^{2}J_{x}^{3} R(f_{f}^{x};h_{k}^{lp};i_{j}^{x};h_{j}^{lp})N_{f}^{x}N_{k}^{lp}d_{i}^{x}d_{j}^{x}: (A5)$$

The factor R is again given by (A 3), because phase-space restrictions are the same as in the previous case,

$$W_{k}^{out} = \frac{x}{\frac{h}{Z}} \frac{(k_{B} T_{x})^{2}}{\frac{1}{x}} M_{k} f^{2}$$

$$\frac{1}{\frac{r}{\frac{x}{i}} \frac{1}{y}} e^{-\frac{x}{r} = k_{B} T_{x}} d_{i}^{x} d_{j}^{x}; \quad (A 6)$$

 $f_{f}^{x}$  can be expressed in term s of  $f_{i}^{x}$ ,  $f_{j}^{x}$ , and the expression in Eq. (14) is obtained.

# APPENDIX B:BOSE-EINSTEIN CONDENSATION IN TWO DIMENSIONS

Let us consider an ensemble of free bosons that follow a Bose-E instein distribution with chem ical potential < 0, and nite temperature T. The density of particles can be evaluated as:

n(;T) = 
$$\frac{1}{2} \int_{0}^{Z_{1}}$$
 () $\frac{d}{e^{(-)=k_{B}T}}$ : (B1)

In 3-D, () /  $p^{-}$ , and the continuous Bose-E instein distribution with = 0 gives a nite critical density  $n_c(T)$ . For densities  $n > n_c(T)$ , all the extra particles fall into the ground state.

In 2-D, =  $m = h^2$  (constant), and the integration in Eq. (B1) diverges as ! 0. For an in nite system, BEC is thus not possible at nite temperature. For a nite system, we can introduce a quantization length,  $L_c$ , such that the integration in Eq. (B1) has a low energy cut o, c:

n(;T) = 
$$\frac{m}{2 h^2} \int_{a}^{2} \frac{1}{e^{(-)=k_{B}T} - 1}$$
: (B2)

For the case  $_{c}=k_{B}T << 1, Eq. (B2)$  gives a very simple result for the maximum density that the 2-D B-E distribution can accommodate:

$$n_{c}(T) = \frac{m k_{B} T}{2 h^{2}} \log \frac{c}{k_{B} T}$$
 (B3)

W henever condition  $n > n_c(T)$  is satisfied, the extra particles added to the system fall into the ground state:

$$\frac{N_{0}(T)}{S} = n \quad n_{c}(T):$$
 (B 4)

For free particles,  $_{\rm c}$  /  ${\rm L_c}^2$ , and Eq. (B2) allows to predict a weak logarithm ic dependence of the critical density on the quantization length. This result qualitatively explains the weak dependence of the critical density on L<sub>c</sub>, obtained in the case of nonequilibrium BEC discussed above.

- [1] A. Im am oglu, R.J. Ram, S. Pau, and Y. Yam am oto, Phys. Rev. A 53, 4250 (1996).
- [2] F.Tassone, C.Piem arocchi, V.Savona, A.Quattropani, and P.Schwendim ann, Phys. Rev. B 56, 7554 (1997).
- [3] M arkusM uller, JoelB leuse, and R egisA ndre, P hys. R ev. B. 62, 16886 (2000).
- [4] R. Huang, F. Tassone, and Y. Yam am oto, Phys. Rev. B 61, R7854 (2000).
- [5] P.G. Savvidis, J.J. Baumberg, R.M. Stevenson, M.S. Skolnick, D.M. W hittaker, and J.S. Roberts, Phys. Rev. Lett. 84, 1547 (2000).
- [6] J.J. Baumberg, P.G. Savvidis, R.M. Stevenson, A.I. Tartakovskii, M.S. Skolnick, D.M. W hittaker, and J.S. Roberts, Phys. Rev. B 62, R16247 (2000).
- [7] C. Ciuti, P. Schwendim ann, B. Deveaud, and A. Quattropani, Phys. Rev. B 62, R 4825 (2000).
- [8] C.Ciuti, P.Schwendim ann, and A.Quattropani, Phys. Rev.B 63,041303 (2001).
- [9] D M .W hittaker, Phys. Rev. B 63, 193305 (2001).
- [10] P.G. Savvidis, J.J. Baumberg, D. Porras, D.M. W hittaker, M S. Skolnick, and J.S. Roberts, Phys. Rev. B 65, 073309 (2002).
- [11] A J. Tartakovskii, M. Em am -Ism ail, R M. Stevenson, M S. Skolnick, V N. A stratov, D M. W hittaker, JJ. Baumberg, and J.S. Roberts, Phys. Rev. B 62, R2283 (2000).
- [12] P. Senellart, J. Bloch, B. Semmage, and J.Y. Marzin, Phys. Rev. B 62, R16263 (2000).
- [13] M D. Mart n, L. Vina, JK. Son, E E. Mendez, Solid State Commun. 117, 267 (2001); ibid. 119, 259 (2001).
- [14] Le SiD ang, D. Heger, R. Andre, F. B uf, and R. Rom es-

tain, Phys. Rev. Lett. 81, 3920 (1998).

- [15] M. Saba, C. Ciuti, J. Bloch, V. Thienry-Mieg, R. Andre, Le SiD ang, S. Kunderm ann, A. Mura, G. Bongiovanni, JL. Staehli, and B. Deveaud, Nature (London) 414, 731 (2002).
- [16] M.Kira, F.Jahnke, S.W.Koch, J.D.Berger, D.V.Wick, T.R.Nelson, Jr., G.Khitrova, and H.M.Gibbs, Phys. Rev.Lett. 79, 5170 (1997).
- [17] G.Khitrova, H.M.Gibbs, F.Jahnke, M.Kira, and S.W. Koch, Rev. Mod. Phys. 71, 1591 (1999).
- [18] F.Tassone and Y.Yam am oto, Phys. Rev. B 59, 10830 (1999).
- [19] A similar ethod has allowed to describe the formation of a Bose-Einstein Condensate in atom ic gases. C W .Gardiner, M D.Lee, R J.Ballagh, M J.Davis, and P.Zoller, Phys. Rev. Lett. 81, 5266 (1998).
- [20] J.J. Baumberg, P.G. Savvidis, P.G. Lagoudakis, M.D. Martin, D. W hittaker, R. Butte, M. Skolnick, and J. Roberts, Physica E, in press.
- [21] G. Malpuech, A. Kavokin, A. Di Carlo, J.J. Baum berg, Phys. Rev. B (2002) in press.
- [22] S.Schm itt-Rink, D S.Chem la, and D A B.M iller, Phys. Rev.B 32, 6601 (1985).
- [23] The term Rabi splitting (<sub>R</sub>), is also used for the polariton splitting in this context. We have changed here the traditional term inology in order to avoid confusion with the case of splitting in a two-level ferm ionic system, where the term Rabi splitting was initially introduced.
- [24] E.Hanamura, J.Phys.Soc.Jpn.29, 50 (1970).
- [25] J.J.Hop eld, Phys. Rev. 112, 1555 (1958).
- [26] A L. Ivanov, P B. Littlewood, and H. Haug, Phys. Rev. B 59, 5032 (1999).
- [27] F.Tassone, C.P. iem arocchi, V.Savona, A.Quattropani, and P.Schwendim ann, Phys. Rev. B 53, R 7642 (1996).
- [28] F. Tassone and Y. Yam am oto, Phys. Rev. A 62, 063809 (2000).
- [29] C. Pierm arocchi, F. Tassone, V. Savona, A. Quattropani, and P. Schwendim ann, Phys. Rev. B. 55, 1333 (1997).
- [30] Su-H uai W ei and A lex Zunger, Phys. Rev. B. 60, 5404 (1999).
- [31] S A .M oschkalenko, and D W .Snoke, Bose-E instein Condensation of Excitons and Biexcitons (Cambridge University Press, Cambridge, 2000).
- [32] Markus Muller, PhD thesis, Grenoble (2000).